The CD54HC158 and CD74HC158 are obsolete and no longer are supplied.

CD54/74HC157, CD54/74HCT157, CD54/74HC158, CD54/74HC158

Data sheet acquired from Harris Semiconductor SCHS153C

September 1997 - Revised October 2003

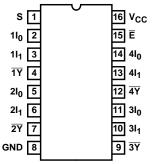
High-Speed CMOS Logic Quad 2-Input Multiplexers

Features

- Common Select Inputs
- Separate Enable Inputs
- · Buffered inputs and Outputs
- Fanout (Over Temperature Range)
 - Standard Outputs...... 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility,
 V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, $I_I \le 1 \mu A$ at V_{OL} , V_{OH}

Pinout

CD54HC157, CD54HCT157, CD54HC158, CD54HCT158 (CERDIP) CD74HC157, CD74HC157, CD74HC158 (PDIP, SOIC) CD74HCT158 (PDIP) TOP VIEW



Description

The 'HC157, 'HCT157, 'HC158, and 'HCT158 are quad 2-input multiplexers which select four bits of data from two sources under the control of a common Select input (S). The Enable input (\overline{E}) is active Low. When (\overline{E}) is High, all of the outputs in the 158, the inverting type, ($\overline{1Y-4Y}$) are forced High and in the 157, the non-inverting type, all of the outputs ($\overline{1Y-4Y}$) are forced Low, regardless of all other input conditions.

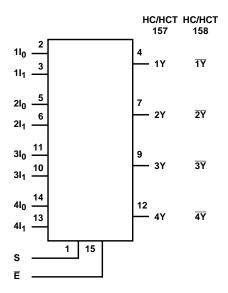
Moving data from two groups of registers to four common output buses is a common use of these devices. The state of the Select input determines the particular register from which the data comes. They can also be used as function generators.

Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC157F3A	-55 to 125	16 Ld CERDIP
CD54HCT157F3A	-55 to 125	16 Ld CERDIP
CD54HCT158F3A	-55 to 125	16 Ld CERDIP
CD74HC157E	-55 to 125	16 Ld PDIP
CD74HC157M	-55 to 125	16 Ld SOIC
CD74HC157MT	-55 to 125	16 Ld SOIC
CD74HC157M96	-55 to 125	16 Ld SOIC
CD74HCT157E	-55 to 125	16 Ld PDIP
CD74HCT157M	-55 to 125	16 Ld SOIC
CD74HCT157MT	-55 to 125	16 Ld SOIC
CD74HCT157M96	-55 to 125	16 Ld SOIC
CD74HCT158E	-55 to 125	16 Ld PDIP

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250

Functional Diagram



TRUTH TABLE

	SELECT			ОИТРИТ			
ENABLE	INPUT	DATA I	NPUTS	157	158		
Ē	s	10	I1	Y	Ÿ		
Н	Х	Х	Х	L	Н		
L	L	L	Х	L	Н		
L	L	Н	Х	Н	L		
L	Н	Х	L	L	Н		
L	Н	Х	Н	Н	L		

H = High Voltage Level, L = Low Voltage Level, X = Don't Care

Absolute Maximum Ratings

Thermal Information

Thermal Resistance (Typical, Note 1)	θ_{JA} (°C/W)
E (PDIP) Package	. 67
M (SOIC) Package	
Maximum Junction Temperature	150 ^o C
Maximum Storage Temperature Range	-65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

Operating Conditions

Temperature Range (T _A)55°C to 125°C
Supply Voltage Range, V _{CC}
HC Types2V to 6V
HCT Types
DC Input or Output Voltage, V _I , V _O
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

		TE: CONDI		v _{cc}		25°C		-40°C 1	O 85°C	-55 ⁰ C T	O 125 ⁰ C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS	
HC TYPES					-		-	-	-				
High Level Input			-	2	1.5	-	-	1.5	-	1.5	-	V	
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V	
				6	4.2	-	-	4.2	-	4.2	-	V	
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V	
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V	
				6	-	-	1.8	-	1.8	-	1.8	V	
High Level Output	VoH	V _{IH} or V _{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V	
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V	
OWIGO Educa			-0.02	6	5.9	-	-	5.9	-	5.9	-	V	
High Level Output	1		-	-	-	-	-	-	-	-	-	V	
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V	
TTE Education			-5.2	6	5.48	-	-	5.34	-	5.2	-	V	
Low Level Output	V _{OL}	V _{IH} or V _{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V	
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V	
OWIGO Educa				0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output	1		-	-	-	-	-	-	-	-	-	V	
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V	
112 20000			5.2	6	-	-	0.26	-	0.33	-	0.4	V	
Input Leakage Current	lı	V _{CC} or GND	-	6	-	1	±0.1	-	±1		±1	μΑ	
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μΑ	

DC Electrical Specifications (Continued)

		TE: CONDI	-	Vcc		25°C		-40°C 1	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(S)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES			-		-		-	-	-			
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	Voн	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lį	V _{CC} and GND	0	5.5	-		±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μΑ
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 2)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μΑ

NOTE:

HCT Input Loading Table

	UNIT LOADS						
INPUT	HCT157	HCT158					
I (All)	0.95	0.4					
Ē	0.6	0.6					
S	3	2.8					

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Table, e.g., 360µA max at $25^{\rm o}C.$

Switching Specifications Input t_r , $t_f = 6ns$

		TEST	V _{CC}	25°C			-40°C T	O 85°C	-55°C T		
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC/HCT157 TYPES											
Propagation Delay (Figure 1)	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	125	-	155	-	190	ns
Data to Output			4.5	-	-	25	-	31	-	38	ns
HC157		C _L =15pF	5	-	10	-	-	-	-	-	ns
HCT157				-	12	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	21	-	26	-	32	ns

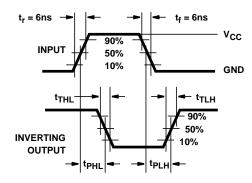
^{2.} For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

Switching Specifications Input $t_{\text{r}},\,t_{\text{f}}$ = 6ns (Continued)

		TEST	Vcc		25°C -4		-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Enable to Output	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	135	-	170	-	205	ns
			4.5	-	-	27	-	34	-	41	ns
HC157	1	C _L =15pF	5	-	11	-	-	-	-	-	ns
HCT157				-	12	-	-	-	-	-	ns
	1	C _L = 50pF	6	-	-	23	-	29	-	35	ns
Select to Output	^t PLH, ^t PHL	C _L = 50pF	2	-	-	145	-	180	-	220	ns
			4.5	-	-	29	-	36	-	44	ns
HC157		C _L =15pF	5	-	12	-	-	-	-	-	ns
HCT157				-	15	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	25	-	31	-	38	ns
Power Dissipation	C _{PD}	-	5								
Capacitance (Notes 3, 4)											_
HC157					62	-	-	-	-	-	pF _
HCT157				-	70	-	-	-	-	-	pF
HC/HCT158 TYPES	I + +	C 50pE	2	Ι.	l -	140	_	175	Ι.	210	no
Data to Output	^t PLH, ^t PHL	C _L = 50pF		_	-		-		-	 	ns
LICATO		0.45=5	4.5	- -		28	-	35	-	42	
HC158		C _L =15pF	5		11	-			-		ns
HCT 158		0 50=5		-	13	-	-	-	-	-	ns
Cashla ta Outaut		C _L = 50pF	6	-	-	24		30	-	36	ns
Enable to Output	^t PLH, ^t PHL	C _L = 50pF	2	-	-	160	-	200	-	240	ns
110450		0 45.5	4.5	-	-	32	-	40	-	48	ns
HC158		C _L =15pF	5	-	13	-	-	-	-	-	ns
HCT 158		0 50 5		-	15	-	-	-	-	-	ns
0.1.44.0.4.4		C _L = 50pF	6	-	-	27	-	34	-	41	ns
Select to Output	^t PLH, ^t PHL	C _L = 50pF	2	-	-	150	-	190	-	225	ns
110450	-	0 45 5	4.5	-	-	30	-	38	-	45	ns
HC158		C _L =15pF	5	-	12	-	-	-	-	-	ns
HCT 158		0		-	14	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	26	-	33	-	38	ns
Output Transition Time	tTLH, tTHL	C _L = 50pF	2	-	-	75	-	95	-	110	ns
			4.5	-	-	15	-	19	-	22	ns
<u> </u>			6	-	-	13	-	16	-	19	ns
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5								
HC158				-	35	-	-	-	-	-	pF
HCT 158				-	35	-	-	-	-	-	pF
Input Capacitance	C _{IN}	$C_L = 50pF$	-	-	-	10	1	10	-	10	pF

- 3. $C_{\mbox{\scriptsize PD}}$ is used to determine the dynamic power consumption, per multiplexer.
- 4. $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where f_i = input frequency, C_L = output load capacitance, V_{CC} = supply voltage.

Test Circuits and Waveforms





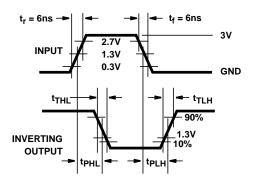


FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC



www.ti.com 13-Jul-2022

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Sample
5962-9070201MEA	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9070201ME A CD54HCT157F3A	Samples
5962-9070301MEA	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9070301ME A CD54HCT158F3A	Samples
CD54HC157F	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD54HC157F	Samples
CD54HC157F3A	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8606101EA CD54HC157F3A	Samples
CD54HCT157F3A	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9070201ME A CD54HCT157F3A	Samples
CD54HCT158F3A	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9070301ME A CD54HCT158F3A	Samples
CD74HC157E	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC157E	Samples
CD74HC157EE4	ACTIVE	PDIP	N	16	25	TBD	Call TI	Call TI	-55 to 125		Sample
CD74HC157M	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC157M	Sample
CD74HC157M96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC157M	Sample
CD74HC157M96E4	ACTIVE	SOIC	D	16	2500	TBD	Call TI	Call TI	-55 to 125		Sample
CD74HC157MT	ACTIVE	SOIC	D	16	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC157M	Sample
CD74HCT157E	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT157E	Sample
CD74HCT157M	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT157M	Sample
CD74HCT157M96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT157M	Sample
CD74HCT157M96E4	ACTIVE	SOIC	D	16	2500	TBD	Call TI	Call TI	-55 to 125		Sample
CD74HCT157MT	ACTIVE	SOIC	D	16	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT157M	Samples

PACKAGE OPTION ADDENDUM

www.ti.com 13-Jul-2022

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD74HCT158E	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT158E	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF CD54HC157, CD54HCT157, CD54HCT158, CD74HC157, CD74HCT157, CD74HCT158;

Catalog: CD74HC157, CD74HCT157, CD74HCT158

PACKAGE OPTION ADDENDUM

www.ti.com 13-Jul-2022

• Military: CD54HC157, CD54HCT157, CD54HCT158

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

www.ti.com 5-Jan-2022

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

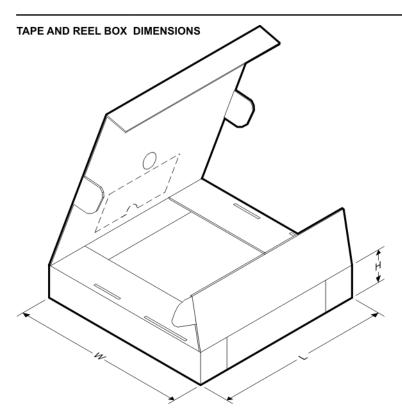
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC157M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT157M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

www.ti.com 5-Jan-2022

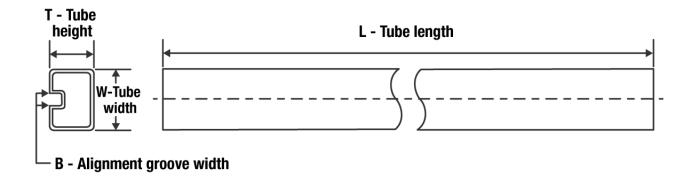


*All dimensions are nominal

Device	Device Package Type		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
CD74HC157M96	SOIC	D	16	2500	340.5	336.1	32.0	
CD74HCT157M96	SOIC	D	16	2500	340.5	336.1	32.0	

www.ti.com 5-Jan-2022

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD74HC157E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC157E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC157EE4	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC157EE4	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC157M	D	SOIC	16	40	507	8	3940	4.32
CD74HCT157E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT157E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT157M	D	SOIC	16	40	507	8	3940	4.32
CD74HCT158E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT158E	N	PDIP	16	25	506	13.97	11230	4.32

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2022, Texas Instruments Incorporated